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Antiferromagnetic metallic state as proved by magnetotransport in epitaxially stabilized perovskite PbRuO {3}

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Abstract

Perovskite PbRuO₃, which has been synthesized only in bulk polycrystalline form under high pressure, is an orthorhombic *Pbnm* at room temperature, exhibiting structural phase transition to *Imma* at around 90 K. This structural transition is accompanied with an orbital ordering and anti-ferromagnetic spin fluctuation. Here, we report the fabrication of single crystalline perovskite PbRuO₃ thin films on various substrates. Magnetotransport measurements reveal that the films have metallic electronic ground state without any clear electronic transitions reported in previous literature. Evidenced by a shift of transition temperature, suppression of magnetic spin fluctuation due to epitaxial strain is implicated. Non-linear Hall effect is also observed with indiscernible hysteresis, plausibly originating from anti-ferromagnetic spins, yet multi-band effect cannot be completely ruled out.

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Transition metal oxide perovskites (ABO_3) are important materials practically used as components in electronic devices and also display a wide range of electronic phenomena such as superconductivity, colossal magnetoresistances, and multi-ferroicity as a result of coupled charge, orbital, and spin orderings [1, 2]. Also in the past several decades, intensive efforts have been made to explore novel functionalities and emergent phenomena in heterostructures composed of transition metal oxides [3]. Among them, perovskite ruthenates (B = Ru) have been studied especially in terms of their metallicity originating from extended broad Ru-4d bands to elucidate correlated itinerant electron physics. All of the pseudocubic ARuO₃ perovskites (A = Ca, Sr, Ba) are metallic to the lowest measured temperatures, while their magnetic properties are largely dependent on A-site. SrRuO₃ and BaRuO₃ are ferromagnets with Curie temperatures $(T_{\rm C})$ of 160 and 60 K, respectively [4–7], while CaRuO₃ does not show a magnetic transition [8]. Different from the rare-earth R^{3+} substitution in perovskite systems such as nickelates [9], the effect on electronic phase in ARuO₃ family cannot be simply predicted from the ionic radius because the substitution induces a significant change in chemistry as well as the size variance [10]. Indeed, the maximum $T_{\rm C}$ is found at SrRuO₃, and any Ca^{2+} or Ba^{2+} substitution for Sr^{2+} results in a reduction of T_C although metallic phase remains to the lowest temperature in this system. In this sense, $PbRuO_3$ (A = Pb) is an interesting compound since Pb²⁺ (1.49 Å) ionic radius locates in between those of Sr^{2+} (1.44 Å) and Ba^{2+} (1.61 Å). Additionally, Pb^{2+} sometimes causes further lattice distortion through "lone pair effect", which can introduce ferroelectricity in such compounds as $PbTiO_3$.

The perovskite PbRuO₃ was first synthesized under 9 GPa and 1,400 °C in 1970 [11], but its low-temperature crystal structure and physical properties were not characterized until a recent report from Kimber et al. in 2009 [12]. They have revealed that PbRuO₃ undergoes a first-order structural transition from the Pbnm phase to the Imma phase on cooling at about 90 K. The local structural distortions resolved from a neutron diffraction study suggested an orbital ordering on Ru in the low temperature Imma phase. This structural phase transition was reported to be concomitant with an electronic phase transition from metal to insulator. Furthermore, PbRuO₃ has no long-range magnetic order down to 1.5 K while presence of anti-ferromagnetic (AFM) spin fluctuation is suggested by a kink-structure in the temperature dependence of magnetic susceptibility. These observations would be surprising because one can naively predict that the perovskite PbRuO₃ is a ferromagnetic metal by

taking into account the aforementioned Pb²⁺ size. They attributed this drastic change in the electronic ground state to a possible orbital order and a hybridization between Pb-6s and Ru-4d electrons, which are also supported by their first-principles calculation in the same report. Soon after their report, J.-G. Cheng et al. have questioned the insulating ground state with no magnetic order of PbRuO₃ and have shown that PbRuO₃ exhibits structural phase transition accompanied with metal-metal transition at around 90 K [13], which is totally different from the previous report by Kimber et al. They have highlighted the uniqueness of the structural phase transition in this system by measuring properties under pressure; in contrast to ordinary perovskite oxides, Imma phase of PbRuO₃ is favorable at lower temperature and suppressed by pressure. Moreover, in later report, they have clarified another crystal phase transition from Pbnm to polar $Pbn\mathcal{Z}_1$ above a critical pressure around 32 GPa [14]. Later, A. F. Kusmartseva et al. have explored quantum criticality of PbRuO₃under high-pressure and clarified that the observed metal-insulator transition by Kimber et al. was an artifact due to the breaking of intergrain connection at the structural transition [15]. They have found the suppression of the transition temperature towards zero at 5 GPa concomitant with an emergence of non-Fermi liquid behavior in resistivity, and the presence of more resistive phase at 30 GPa and ambient temperature.

As introduced above, regardless of numbers of intriguing physical phenomena, magneto-transport properties have not been reported in PbRuO₃ because of the difficulty in synthesizing single crystal. With using considerable size of single crystalline thin films, well-defined Hall-bar device structure can be fabricated in order to clarify the magnetotransport properties. Also, in thin films, we have the possibility to control the physical properties of PbRuO₃ by epitaxial strain, because phase transition in bulk is seemingly affected by pressure [13–15]. Our transport studies for thin films reveal a metallic ground state of PbRuO₃ and emergence of non-linear Hall effect, although any clear signature of the crystal phase transition has not been observed.

Single crystalline PbRuO₃ thin films were prepared on various substrates by pulsed laser deposition (PLD). The target was prepared in ambient by the solid-state reaction of PbO and RuO₂ at 1,100 °C in stoichiometric proportions, resulting in single phase pyrochlore Pb₂Ru₂O_{6.5}. Although perovskite PbRuO₃ is a meta-stable phase and cannot be obtained by a simple solid state reaction at ambient pressure, we succeeded in fabrication of single crystalline thin films starting from the pyrochlore Pb₂Ru₂O_{6.5} target after optimizing growth

conditions. First, a series of films were deposited on SrTiO₃ (001) substrate to optimize growth conditions. A KrF laser with a pulse frequency of 5 Hz and fluence of $\approx 2 \text{ J/cm}^2$ was employed while changing the growth temperature and oxygen partial pressure. SrTiO₃ substrate was annealed in-situ at 900 °C under 10^{-5} Torr O_2 to obtain clear step-terrace structure with single-unit-cell height. General temperature-pressure phase diagram is shown in Fig. 1, which can be classified into five regions based on X-ray diffraction. At high temperature and high oxygen partial pressure (region A), no film is obtained probably because precursors are re-evaporated as volatile RuO₃ and PbO. At high oxygen partial pressure but lower temperature (region B), PbO_x is formed. On the other hand, at lower oxygen partial pressure but high temperature (region C), RuO₂ is formed. When both temperature and oxygen partial pressure are low (region D), we cannot observe any X-ray diffraction peaks although we can see some film is deposited on the substrate, indicating that precursors form amorphous film due to the lack of formation energy. In the intermediate region (region E), both Pb₂Ru₂O_{6.5} and targeted perovskite PbRuO₃ phases appear. Second, within the region E, in order to suppress the formation of Pb₂Ru₂O_{6.5} phase, we reduce the laser frequency to slow down the growth rate. Finally, we reach the optimum growth conditions, and films are deposited on various substrates at 450 °C under 0.1 m Torr O₂ with a pulse frequency of 1 Hz and fluence of $\approx 2 \text{ J/cm}^2$, where typical growth rate is ≈ 0.01 Å/sec.

Having established the optimum growth conditions, we employed (LaAlO₃)_{0.3} (SrAl _{0.5} Ta _{0.5} O ₃)_{0.7} (LSAT) (001) (cubic, 3.867 Å), SrTiO₃ (STO) (001) (cubic, 3.905 Å), DyScO₃ (DSO) (110) (orthorhombic, 3.942 Å in pseudocubic setting), and GdScO₃ (GSO) (110) (orthorhombic, 3.967 Å in pseudocubic setting). Bulk PbRuO₃ has orthorombic crystal structure with a = 5.563 Å, b = 5.614 Å, and c = 7.865 Å, thus it can be seen as a pseudocubic structure with $a_{pc} = 3.945$ Å. Therefore, PbRuO₃ is subjected to compressive strains of -1.98, -1.02, and -0.07% on LSAT, STO, and DSO, and tensile strains of +0.39% on GSO respectively. In prior to the growth on LSAT, DSO and GSO substrates, 2 nm STO buffer layer was deposited at 600 °C under 0.1 m Torr O₂ environment, in order to ensure smoother surface and to relieve the valence discontinuity between these substrates with PbRuO₃, which is often crucial to obtain thermodynamically unstable compounds such as SrMoO₃ [16] and EuMoO₃ [17, 18]. Electric conductivity of the STO buffer layer was examined to reveal that STO grown under the same condition was insulating. Thickness

of the PbRuO₃ films were around 10 nm for LSAT, DSO and GSO samples, and around 5 nm for STO sample, which were confirmed by X-ray reflectivity measurements. The magnetotransport properties were obtained with using a liquid He cryostat equipped with a 9 T superconducting magnet (PPMS, Quantum Design Co.). Magnetic field is applied perpendicular to the films. Longitudinal (ρ_{xx}) and Hall resistivity (ρ_{H}) are deduced by a conventional symmetrization and anti-symmetrization procedures, respectively.

X-ray diffraction (XRD) 2θ - ω scans and magnified XRD patterns around (002) (pseudocubic setting) peak of PbRuO₃ films are presented in Figs. 2(a) and 2(b). The (002) peaks of PbRuO₃ are indicated by triangles, and they shift from lower to higher 2θ angle as the lattice constant of the substrate increases, indicating that the out-of-plane lattice constant ($a_{\rm op}$) changes by the epitaxial strains. The rocking curve (not shown) width is less than 0.1° for all the films, also indicating high orientation and crystallinity. Epitaxial relationships between the substrates and PbRuO₃ films are also clarified by reciprocal space mappings presented in Fig. 2(c), where in-plane lattice constants of PbRuO₃ match up with those of all the substrates. These results are summarized in Fig. 2(d). The theoretical line for $a_{\rm op}$ of strained PbRuO₃ films can also be calculated from Young's modulus as shown in Fig.2(d), by assuming fully strained situation, where the Possion's ratio $\nu \approx 0.41$ is deduced as a fitting parameter.

In order to elucidate the strain effect on the electronic phase of PbRuO₃, electrical transport measurements were performed. For these measurements, films were processed to Hallbar structure with a standard photolithography technique especially to acquire precise $\rho_{\rm H}$ with less intermixing from ρ_{xx} ; Hall-bar structure was fabricated by Ar ion-milling, and then Ni (10 nm)/Au (50 nm) electrode was attached by electron beam evaporation (Fig. 3(a)). Because Ar ion-milling process introduces oxygen vacancies to STO substrate and makes it conducting, we will discuss magnetotransport properties of PbRuO₃ on LSAT, DSO, and GSO substrates, hereafter.

Temperature dependence of ρ_{xx} are presented in Fig. 3(b). At room temperature, ρ_{xx} of all the films is almost in the same order of magnitude (10⁻⁴ Ω cm), which is consistent with the previous report for high-pressure synthesized bulk samples [13–15]. ρ_{xx} show metallic temperature dependence down to 2 K with residual resistivity ratio (RRR $\equiv \rho_{xx}(300K)/\rho_{xx}(2K)$) of ≈ 1.5 , indicating that the RRR of our films are lower than those of bulk samples. Different from previous literature data by both groups, our films do not

exhibit an obvious signature of transition at around 90 K as shown in the temperature derivative of ρ_{xx} (Fig. 3(c)). Temperature hysteresis of ρ_{xx} is also carefully checked around 90 K but not detected, either. This apparent absence of the phase transition can be explained by the epitaxial strain because the transition is concomitant with structural transition. The lower RRR may also be attributed to the strain effect because the reduction of RRR has been reported for the bulk sample as applying statistic pressure [13–15].

Magnetic field (B) dependence of magnetoresistance ratio (MRR(%) $\equiv [\rho_{xx}(B)/\rho_{xx}(0) - 1] \times 100$) obtained at various temperatures are presented in Fig. 4(a). All the films exhibit a slight positive magnetoresistance (MR) at lower temperatures, 0.3–0.6% at 2 K under B=9 T. Intriguing feature here is the deviation from conventional quadratic ($\sim B^2$) positive MR, which is clearly seen for PbRuO₃ on DSO and GSO. One explanation can be given by considering a competition between the positive quadratic MR and negative MR from spin canting which will be enhanced by magnetic field. Another possible reason is weak anti-localization (WAL) effect, which comes from quantum interference of scattered electrons through spin-orbit-coupling (SOC) [19, 20]. Although WAL effect has been recently well established in magnetotransport properties in topological materials [21, 22], it is a generic characteristic of the materials with strong SOC. Indeed, positive MR due to WAL or anisotropic MR has been reported for SrRuO₃ owing to relatively large SOC [23]. In PbRuO₃, band structure near Fermi level consists of hybridized Pb-6s and Ru-4d orbitals as suggested by theoretical calculations [12, 14], thus heavy Pb atom may enhance SOC and lead to the observed non-quadratic MR.

As temperature goes up, MRR becomes smaller, changes its sign, and shows bottom, where negative MR becomes maximum, before it becomes negligibly small at around 100 K as shown in Fig. 4(b). This transition in MR can be understood by considering the AFM spin fluctuation previously reported [12, 13], which occurs concomitant with the structural transition at 90 K (= $T_{\rm sf}$). At lower temperatures, spin fluctuation is suppressed and positive MR is dominant. With increasing temperature, spin fluctuation is thermally activated more, thus applied magnetic fields yield negative MR by suppressing the magnetic scattering on conduction electrons. Therefore, the change of the bottom position can be interpreted as the change of $T_{\rm sf}$. $T_{\rm sf}$ has been reported to become lower under hydrostatic pressure for polycrystalline PbRuO₃ [13]. Interestingly in Fig. 4(b), the bottom position of most strained PbRuO₃ on LSAT substrate is remarkably lower than those of others. Although

epitaxial strain is not equivalent with static pressure, we can speculate the observed shift in the bottom position results from the suppression in $T_{\rm sf}$.

Now we discuss Hall effect, which can detect the magnetic properties because conduction electrons sensitively capture the magnetization in the form of non-linear Hall effect. Hall resistivity ($\rho_{\rm H}$) can generally be written as $\rho_{\rm H}=R_{\rm H}B+R_{\rm A}M+\rho_{\rm T}$, where the first is ordinarily Hall term with Hall coefficient $R_{\rm H}$, the second is anomalous Hall term proportional to magnetization (M) with coefficient $R_{\rm A}$, and the third is topological Hall term arising from quantum fictitious magnetic flux [24, 25]. In our films, at higher temperature, $\rho_{\rm H}$ is merely linear to B, but it becomes non-linear as temperature goes lower. However, we need to carefully consider the multi-bad effect as an origin of non-linear Hall effect, which is discussed later.

Figure 5 displays the magnetic field dependence of ρ_{xx} and ρ_{H} and their magnetic field derivative at 2 K for the PbRuO₃ films grown on the various substrates. Peak structures are commonly observed in $d\rho_{xx}/dB$ at around 1–2 T, although that of PbRuO₃ on LSAT is broader than those of others. This indicates that, at lower temperature, ρ_{xx} deviates from quadratic behavior which is expected for MR originating from Lorentz force as we already discussed. As for $\rho_{\rm H}$, the raw data hardly exhibit non-linearity as shown in the bottom panels. However, by taking derivatives $(d\rho_H/dB)$, non-linear Hall effect has been clearly seen. Intriguingly, for PbRuO₃ on DSO and GSO, peak structures appear and their positions match with those of $d\rho_{xx}/dB$, which cannot be explained only by multi-band effect and is suggestive of some contribution from magnetic spins, namely, anomalous Hall effect. On the other hand, different from the case of conventional anomalous Hall effect in ferromagnets, $d\rho_H/dB$ is not fully saturated even at 9 T. This can be explained by two possibilities; (i) non-linearity comes from anomalous Hall effect, and because of the anti-ferromagnetic spin fluctuation, much higher magnetic field is demanded for complete saturation, (ii) nonlinearity does not come from anomalous Hall effect but from multi-band effect. Considering the properties of PbRuO₃, it is challenging to clearly distinguish these two origins.

Finally, we have attempted to fit the $\rho_{\rm H}(B)$ data by conventional two-carrier model written as below to estimate the multi-band effect; $\rho_{\rm H}(B) = [(\mu_1^2 n_1 + \mu_2^2 n_2) + (\mu_1 \mu_2 B)^2 (n_1 + n_2)]B/e[(\mu_1|n_1|+\mu_2|n_2|)^2 + (\mu_1\mu_2 B)^2 (n_1+n_2)^2]$, where $n_{\rm i}$ and $\mu_{\rm i}$ denote density and mobility for each carrier, respectively. Based on this equation, we have fitted the $\rho_{\rm H}(B)$ data with the constraint of $\rho_{xx}(0) = 1/e(n_1\mu_1 + n_2\mu_2)$. The observed non-linearity of $\rho_{\rm H}$, including overall

trend of $d\rho_H/dB$, are well captured by the fitted curves in Fig. 5 considering two types of electrons. However, the fitted curves fail to reproduce the characteristic peaks observed in PbRuO₃ on DSO and GSO, indicating that the peak structures do not originate from multi-band effect. Moreover, in order to fit the $\rho_H(B)$ data, we need to assume the existence of minority carrier with quite high mobility, as high as $\approx 1,000 \text{ cm}^2/\text{V} \cdot \text{s}$, which is unphysical for such complex oxides. We have performed the same fitting for $\rho_H(B)$ data obtained at 5 and 10 K, and confirmed the overall trend is well reproduced, although the peaks diminish rapidly at higher temperatures. (See Supplemental Information at [26] for detail). From these reasons, we can fairly postulate that some magnetic transition occurs in our PbRuO₃ films at lower temperature and anomalous Hall effect emerges under applied magnetic fields. Yet, further investigation for magnetization is required to unveil this issue.

In conclusion, high-pressure phase of perovskite PbRuO₃ has been successfully synthesized as single crystalline thin films on various substrates with different epitaxial strains by PLD. Opposed to previous studies for bulk polycrystalline samples of PbRuO₃ grown under high pressure, clear transition has not been observed in ρ_{xx} on cooling temperature possibly because of the suppression of the structural transition by the epitaxial strains. Magnetotransport measurements clarify the strain effect on the electronic state of PbRuO₃, and suppression of AFM spin fluctuation is implicated by magnetoresistance, which is consistent with the reported pressure induced transition for bulk samples. Non-linear Hall effect is also observed, which is presumably due to anomalous Hall effect emerging from AFM spins. Our present work will be supported by further studies especially in terms of magnetism to clarify the intriguing properties of this unusual perovskite ruthenate.

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^[1] Y. Tokura, Reports on Progress in Physics 69, 797 (2006).

^[2] K. F. Wang, J. M. Liu, and Z. F. Ren, Advances in Physics 58, 321 (2009).

^[3] H. Y. Hwang, Y. Iwasa, M. Kawasaki, B. Keimer, N. Nagaosa, and Y. Tokura, Nature materials 11, 103 (2012).

^[4] J. M. Longo, P. M. Raccah, and J. B. Goodenough, Journal of Applied Physics 39, 1327

(1968).

- [5] D. J. Singh, Journal of Applied Physics **79**, 4818 (1996).
- [6] I. Mazin and D. Singh, Physical Review B 56, 2556 (1997).
- [7] C. Q. Jin, J. S. Zhou, J. B. Goodenough, Q. Q. Liu, J. G. Zhao, L. X. Yang, Y. Yu, R. C. Yu, T. Katsura, A. Shatskiy, and E. Ito, Proceedings of the National Academy of Sciences of the United States of America 105, 7115 (2008).
- [8] L. Klein, L. Antognazza, T. H. Geballe, M. R. Beasley, and A. Kapitulnik, Physical Review B 60, 1448 (1999).
- [9] J. Torrance, P. Lacorre, A. Nazzal, E. Ansaldo, and C. Niedermayer, Physical Review B 45, 8209 (1992).
- [10] J. G. Cheng, J. S. Zhou, J. B. Goodenough, and C. Q. Jin, Physical Review B 85, 184430 (2012).
- [11] J. A. Kafalas and J. M. Longo, Materials Research Bulletin 5, 193 (1970).
- [12] S. A. Kimber, J. A. Rodgers, H. Wu, C. A. Murray, D. N. Argyriou, A. N. Fitch, D. I. Khomskii, and J. P. Attfield, Physical Review Letters 102, 046409 (2009).
- [13] J. G. Cheng, J. S. Zhou, and J. B. Goodenough, Physical Review B 80, 174426 (2009).
- [14] J. G. Cheng, K. E. Kweon, J. S. Zhou, J. A. Alonso, P. P. Kong, Y. Liu, C. Jin, J. Wu, J. F. Lin, S. A. Larregola, W. Yang, G. Shen, A. H. MacDonald, A. Manthiram, G. S. Hwang, and J. B. Goodenough, Proceedings of the National Academy of Sciences of the United States of America 110, 20003 (2013).
- [15] A. F. Kusmartseva, A. Sinclair, J. A. Rodgers, S. A. Kimber, and J. P. Attfield, Physical Review B 87, 165130 (2013).
- [16] A. Radetinac, J. Zimmermann, K. Hoyer, H. Zhang, P. Komissinskiy, and L. Alff, Journal of Applied Physics 119, 055302 (2016).
- [17] Y. Kozuka, H. Seki, T. C. Fujita, S. Chakraverty, K. Yoshimatsu, H. Kumigashira, M. Oshima, M. S. Bahramy, R. Arita, and M. Kawasaki, Chemistry of Materials 24, 3746 (2012).
- [18] T. C. Fujita, Y. Kozuka, H. Seki, and M. Kawasaki, Physical Review B 87, 205402 (2013).
- [19] S. Hikami, A. I. Larkin, and Y. Nagaoka, Progress of Theoretical Physics 63, 707 (1980).
- [20] J. J. Lin and J. P. Bird, Journal of Physics Condensed Matter 14, R501 (2002).
- [21] M. Z. Hasan and C. L. Kane, Reviews of Modern Physics 82, 3045 (2010).
- [22] X. L. Qi and S. C. Zhang, Reviews of Modern Physics 83, 1057 (2011).

- [23] R. Gunnarsson, Physical Review B 85, 235409 (2012).
- [24] N. Nagaosa, J. Sinova, S. Onoda, A. H. MacDonald, and N. P. Ong, Reviews of Modern Physics 82, 1539 (2010).
- [25] J. Sinova, S. O. Valenzuela, J. Wunderlich, C. H. Back, and T. Jungwirth, Reviews of Modern Physics 87, 1213 (2015).
- [26] Supplemental Information.

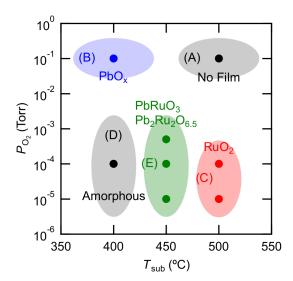


FIG. 1. Growth phase diagram of PbRuO₃thin films. Depending on the growth temperature (T_{sub}) and oxygen partial pressure (P_{O_2}) , the diagram classifies following five regions. (A) both Pb and Ru are evaporated. (B) Ru evaporates as volatile RuO₃ and only PbO_x remains. (C) Pb evaporates as volatile PbO and only RuO₂ remains. (D) Both Ru and Pb are in amorphous phase. (E) Coexistence region of stable Pb₂Ru₂O_{6.5} and meta-stable PbRuO₃ phases.

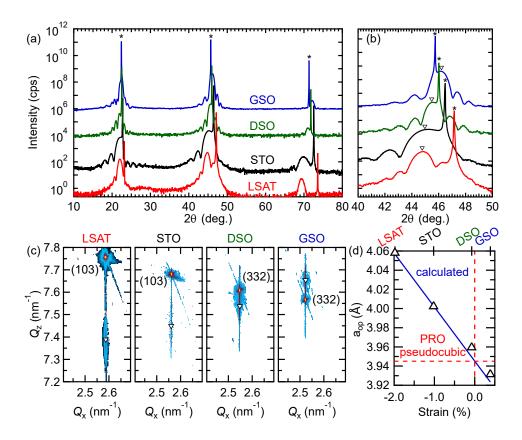


FIG. 2 (Color online). (a) X-ray diffraction (XRD) 2θ - ω scans and (b) magnified data around the (002) (pseudocubic setting) peak of PbRuO₃ films on different substrates. The peaks of substrates and PbRuO₃ films are denoted by stars and triangles, respectively. (c) Reciprocal space maps (RSM) for PbRuO₃ films around (103) peak of LSAT and STO substrates, and around (332) peak of DSO and GSO substrates. PbRuO₃ films peaks are denoted by triangles. (d) Out-of-plane lattice constant (a_{op}) for PbRuO₃ films on different substrates. The dashed red lines represent the pseudocubic lattice constants for bulk PbRuO₃. The blue line represents the strained a_{op} of PbRuO₃ films estimated from a Young's modulus of 0.41.

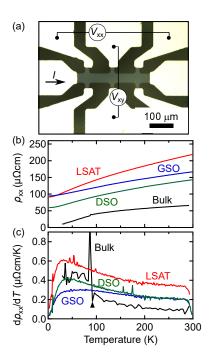


FIG. 3 (Color online). (a) Device structure for magnetotransport measurements. (b) Temperature dependence of longitudinal resistivity ρ_{xx} and (c) its temperature derivative for PbRuO₃ films grown on the different substrates. The bulk data are from Ref. [13]. The triangle indicates the transition temperature of the bulk sample.

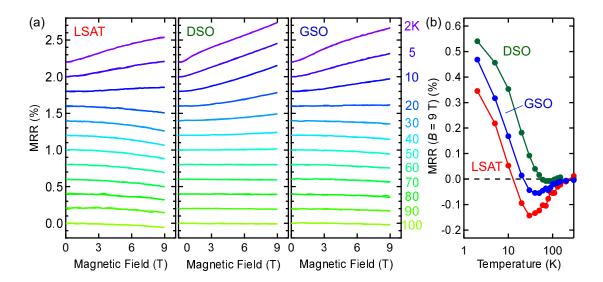


FIG. 4 (Color online). (a) Magnetic field dependence of the magnetoresistance ratio (MRR) of PbRuO₃ films grown on the different substrates. The data are shifted vertically by 0.2% for clarity. (b) Temperature dependence of MRR values at +9 T.

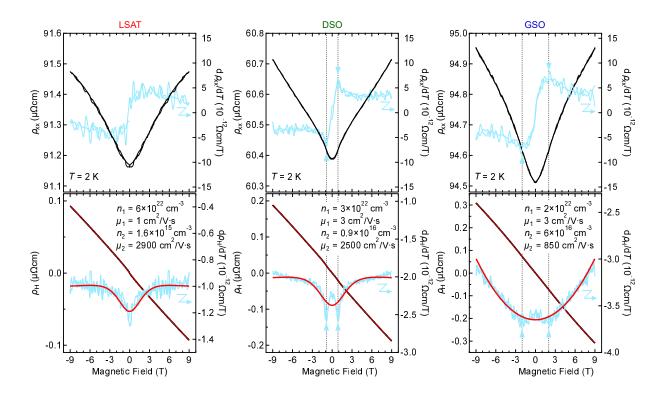


FIG. 5 (Color online). Magnetic field (B) dependence of (top panels) ρ_{xx} and (bottom panels) $\rho_{\rm H}$ at 2 K for PbRuO₃ films grown on the different substrates. Magnetic field derivative is also shown in right axis of each panel. The triangles and the dotted lines indicate the peak position of $d\rho_{xx}/dB$. The solid red lines in the bottom panels are fitted curves using the two-carrier model. Deduced density and mobility of majority (n_1, μ_1) and minority (n_2, μ_2) carriers are indicated.